

ENERGY GAP STRUCTURE AND TUNNELING CHARACTERISTICS
OF LAYERED SUPERCONDUCTORS*

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OF LAYERED SUPERCONDUCTORS

by

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Abstract

We have analyzed the energy gaps and density-of-states (DOS) of layered superconductors with two inequivalent layers in a unit cell along the *c*-axis. In the physically interesting parameter range where the interlayer hopping strengths of the quasiparticles are comparable to the critical temperature, the peaks in the DOS curve do not correspond to the order parameters (OP's) of each layer, but depend on the OP's and the interlayer hopping strengths in a complex manner. In contrast to a BCS superconductor, the DOS of layered systems have logarithmic singularities. Our simulated tunneling characteristics bear close resemblance to experimental results.

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1. Introduction

All copper oxide based high- T_c superconductors have stratified structures, in which the quasiparticles move freely within the layers but hop weakly between layers. It has occurred to a number of authors that the nearly two-dimensional geometry may play an important role in the phenomenology of these materials [1-8]. Much of this effort has been stimulated by the tunneling spectroscopy data, which exhibit far more complex structure than low- T_c superconductors. In general, the theories predict that in the weak hopping limit in which the interlayer hopping strengths of the quasiparticles are weak compared with the critical temperature T_c , the DOS curves have peaks at the energy gaps or order parameters of individual layers [1-2]. In the strong hopping limit, however, the main features in the DOS curve should be identified with the OP's of the bands [3-5]. The present work carries this line of inquiry into the interesting and perhaps most relevant parameter range, namely, where the hopping strengths are comparable to the OP's or T_c . For simplicity, we limit our work to two distinct layers in a unit cell with intralayer or interlayer pairing. It is found that the results of both weak hopping and strong hopping theories are incomplete and potentially misleading. The features in DOS are not directly identifiable with the OP's of the layers, but are shifted and modified by the band dispersion along the c -direction. The singularities in DOS curves are logarithmic, which are less pronounced than those for BCS superconductors. We conclude that the tunneling curves for layered superconductors should be interpreted with caution.

The paper is organized as follows. Section 2 contains the analysis of a two-layer intralayer pairing model, showing the basic algebraic steps leading to our new conclusions. Section 3 extends the consideration to the interlayer pairing case. Section 4 discusses how the results of the last two sections may be applied to real systems.

2. The Intralayer Pairing Model

The model consists of two conducting layers in a unit cell with identical two-dimensional band structures and interlayer hopping strengths J_1 and J_2 . The quasiparticles within the same layer interact via a phenomenological pairing interaction of the BCS type so that the total Hamiltonian has the form $H = H_0 + V$, where the band energy term is

$$H_0 = \sum_{j\mathbf{k}\sigma} \sum_{n=1}^2 \xi_0(\mathbf{k}) \psi_{jn\sigma}^\dagger(\mathbf{k}) \psi_{jn\sigma}(\mathbf{k}) + \sum_{j\mathbf{k}\sigma} [J_1 \psi_{j1\sigma}^\dagger(\mathbf{k}) \psi_{j2\sigma}(\mathbf{k}) + J_2 \psi_{j2\sigma}^\dagger(\mathbf{k}) \psi_{j+1,1\sigma}(\mathbf{k}) + H.c.], \quad (1)$$

where $\xi_0(\mathbf{k}) = \mathbf{k}^2/2m_0 - E_F$, $\mathbf{k} = (k_x, k_y)$, σ is the spin index, $n = 1, 2$ is the layer index within a unit cell, and the sum on j is over all unit cells normal to the planes. The units are chosen such that $\hbar = k_B = 1$. The interaction term is

$$V = -\frac{1}{2} \sum_{jn} \sum_{\mathbf{k}\sigma} \sum_{\mathbf{k}'\sigma'} \lambda_{0n} \psi_{jn\sigma}^\dagger(\mathbf{k}) \psi_{jn\sigma'}^\dagger(-\mathbf{k}) \psi_{jn\sigma'}(-\mathbf{k}') \psi_{jn\sigma}(\mathbf{k}'), \quad (2)$$

where we assume two unequal pair coupling strengths λ_{0n} , both are cut off at a common energy $\omega_{||}$. The condition $\sigma' = -\sigma$ will be imposed, since the pair coupling mechanism only allows singlet pairs. The model has been generalized to two layers with different two-dimensional band structures and different Fermi surfaces [7], but the simpler model considered here gives a clearer physical picture.

The quasiparticle Green's function matrix elements are defined in the familiar way:

$$G_{nn'}(k, \tau - \tau') = -\langle T[\psi_{n\sigma}(k, \tau) \psi_{n'\sigma}^\dagger(k, \tau')]\rangle, \\ F_{nn'}(k, \tau - \tau') = \langle T[\psi_{n\sigma}(k, \tau) \psi_{n',-\sigma}(-k, \tau')]\rangle, \quad (3)$$

where $k = (\mathbf{k}, k_z)$, k_z is the crystal momentum in the c -direction, $\langle \dots \rangle$ denotes thermal average, and

$$\psi_{n\sigma}(k) = \Omega^{1/2} \sum_{k_z} \psi_{jn\sigma}(\mathbf{k}) e^{ik_z[js + (n-1)d]}. \quad (4)$$

In the above equation Ω is the volume of the crystal, s is the thickness of the unit cell in the c -direction, and d is the separation between layer 1 and layer 2 within the same cell. The separation between adjacent layers in adjacent cells will be denoted by $d' = s - d$. The spin index is suppressed in the Green's function matrix elements. We define two order parameters Δ_n , for $n = 1, 2$, by

$$\Delta_n = \lambda_{0n} \sum_{\mathbf{k}'} \langle \psi_{n\sigma}(\mathbf{k}') \psi_{n,-\sigma}(-\mathbf{k}') \rangle. \quad (5)$$

The inverse of the Green's function matrix has the form

$$\hat{G}^{-1}(\mathbf{k}, \nu) = \begin{pmatrix} i\nu - \xi_0(\mathbf{k}) & -g(k_z) & \Delta_1 & 0 \\ -g^*(k_z) & i\nu - \xi_0(\mathbf{k}) & 0 & \Delta_2 \\ \Delta_1^* & 0 & i\nu + \xi_0(\mathbf{k}) & g(k_z) \\ 0 & \Delta_2^* & g^*(k_z) & i\nu + \xi_0(\mathbf{k}) \end{pmatrix}, \quad (6)$$

where the quantity

$$g(k_z) = J_1 e^{ik_z d} + J_2 e^{-ik_z d'} \equiv \epsilon_{\perp}(k_z) e^{-i\phi(k_z)}, \quad (7)$$

with

$$\epsilon_{\perp}(k_z) = [J_1^2 + J_2^2 + 2J_1 J_2 \cos k_z s]^{1/2}, \quad (8)$$

$$\phi(k_z) = \frac{J_2 \sin k_z d' - J_1 \sin k_z d}{J_2 \cos k_z d' + J_1 \cos k_z d}. \quad (9)$$

The functions $\pm \epsilon_{\perp}(k_z)$ represent the dispersion of the two tight-binding bands in the c -direction.

The inversion of the Green's function matrix is tedious but straightforward. Putting the results in Eq.(3), we deduce the following gap equations:

$$\Delta_1 = \frac{\lambda_{01}}{\beta} \sum_{\mathbf{k}\nu} \frac{1}{D} \{ [\nu^2 + \xi_0^2(\mathbf{k})] \Delta_1 + \epsilon_{\perp}^2(k_z) \Delta_2 + |\Delta_2|^2 \Delta_1 \}, \quad (10)$$

where $\beta = 1/T$, T is the temperature, and the sum over ν is over the Matsubara frequencies under the constraint that $|\nu| < \omega_{\parallel}$. The equation for Δ_2 is similar except for an exchange

of indices 1 and 2. The quantity D is the determinant of the inverse Green's function matrix:

$$D = (\nu^2 + \xi_0^2)^2 + 2\epsilon_\perp^2(\nu^2 - \xi_0^2) + \epsilon_\perp^4 + (|\Delta_1|^2 + |\Delta_2|^2)(\nu^2 + \xi_0^2) + \epsilon_\perp^2(\Delta_1^* \Delta_2 + \Delta_1 \Delta_2^*) + |\Delta_1 \Delta_2|^2. \quad (11)$$

As discussed in Ref. 3 – 5, in the state with minimum free energy the two order parameters are in phase.

The first step toward reducing the gap equations is to integrate over the two-dimensional crystal momentum \mathbf{k} . The results appear more compact in terms of the following set of new variables and parameters:

$$\Delta_\pm = \frac{1}{2}(\Delta_1 \pm \Delta_2), \quad (12)$$

and

$$\lambda_\pm = \frac{1}{2}(\lambda_{01} \pm \lambda_{02}). \quad (13)$$

We find

$$\Delta_\pm = \frac{\pi}{\beta} \sum_\nu \int \frac{sd\mathbf{k}_x}{2\pi} \frac{1}{2c} \left\{ \lambda_\pm N(0) \left[\frac{c + \Delta_-^2 - \epsilon_\perp}{\sqrt{\nu^2 + a_+}} + \frac{c - \Delta_-^2 + \epsilon_\perp}{\sqrt{\nu^2 + a_-}} \right] \Delta_+ + \lambda_\mp N(0) \left[\frac{c + \Delta_+^2}{\sqrt{\nu^2 + a_+}} + \frac{c - \Delta_+^2}{\sqrt{\nu^2 + a_-}} \right] \Delta_- \right\}, \quad (14)$$

where $N(0) = m_0/2\pi s$ is the density of states per band,

$$c = [\Delta_+^2 \Delta_-^2 - \epsilon_\perp(\Delta_+^2 + \nu^2)]^{1/2}, \quad (15)$$

and

$$a_\pm = \Delta_+^2 + \Delta_-^2 - \epsilon_\perp^2 \pm 2c. \quad (16)$$

In the last step the sum over Matsubara frequencies is analytically continued into an integral over real frequencies ω . The resulting integral equations are solved numerically for $\Delta_n(T)$.

The critical temperature T_c is solved from the linearized version of Eq.(14). A brief summary of the results, which are discussed in detail in Ref. 6 and 8, is as follows. In the limit of zero hopping the critical temperature is solved from

$$\lambda_> N(0) a_{||}(T_{c0}) = 1, \quad (17)$$

where $\lambda_>$ is the larger of the two λ_{0n} and $a_{||}(T) = \ln(2\gamma\omega_{||}/\pi T)$, $\gamma = 1.78$. With increasing hopping T_c is lowered steadily from the zero hopping limit T_{c0} . In the limit of strong hopping, i.e. $J_n \gg \omega_{||}$, the critical temperature is solved from

$$\lambda_+ N(0) a_{||}(T_c) = 1, \quad (18)$$

with λ_+ defined in Eq.(12).

The OP's at zero temperature depend also on the hopping strengths. In the zero hopping limit the equations separate into two independent equations whose solutions are the gaps for the individual layers. With increasing hopping the larger of the two solutions, which is designated as Δ_1 , decreases while the smaller one, Δ_2 increases. Thus, the two layers are more similar to each other in their superconducting properties. In the strong hopping limit, we find that the ratio of the gaps satisfies $\Delta_1/\Delta_2 = \lambda_1/\lambda_2$. The average gap Δ_+ defined in Eq.(12) is the energy gap of the energy bands. These results are summarized in Fig.1 for a set of parameters $\lambda_{02}/\lambda_{01} = 0.7$, $\lambda_{01}N(0) = 0.5$, $J_2/J_1 = 0.3$, and J_1/T_{c0} ranging from 0.1 to 10.

In Fig.2 we show $\Delta_n(T)$, $n = 1, 2$, for the same of model parameters except that $J_1/T_{c0} = 1$. For these parameters the critical temperature $T_c = 0.92T_{c0}$. The dominant OP Δ_1 has the typical BCS behavior. The lesser OP Δ_2 initially behaves as if it is heading toward a critical temperature lower than T_c , but turns around to follow Δ_1 above $0.6T_c$, where superconductivity in layer 2 is induced by the proximity effect. This result is typical for systems with two or more coupled order parameters.

The density-of-states in the superconducting state is calculated in the standard way:

$$N_s(\omega) = \frac{1}{\pi} \sum_{kn} \text{Im} G_{nn}(k, \nu) |_{\nu \rightarrow -i\omega + \delta}, \quad (19)$$

where $\delta = 0^+$. After integrating over k , we find

$$N_s(\omega) = N(0) \int \frac{sdk_z}{2\pi} \text{Im} \frac{-i\nu}{2c} \left[\frac{c - \epsilon_1^2}{\sqrt{\nu^2 + a_+}} + \frac{c + \epsilon_1^2}{\sqrt{\nu^2 + a_-}} \right]_{\nu \rightarrow -i\omega + \delta}, \quad (20)$$

where the quantities c and a_{\pm} are defined in Eqs.(14) and (15). We show in Fig.3 a set of total DOS curves at zero temperature for the same set of model parameters in Fig.1 with J_1/T_{c0} ranging from a weak hopping value of 0.1 to a strong hopping value of 5. The calculated $\Delta_{1,2}$ are marked on the graph with two kinds of arrows. The four curves are displaced vertically by 2 units successively. It can be seen that in the weak hopping case; the bottommost curve, the DOS has two sets of peaks corresponding to the OP's of the two layers, in agreement with the conclusions of Refs. 1 and 2. Each set resembles the BCS result. The system may be regarded as two nearly independent superconductors, each with its own energy gap. The strong hopping case, the topmost curve, the peaks are situated halfway between Δ_1 and Δ_2 , i.e. the position of Δ_+ , in agreement with Refs. 3-5. The two middle curves for intermediate hopping do not conform to either physical picture. In particular, for $J_1/T_{c0} = 1$, we find $N_s(\omega) = 0$ for $\omega < \omega_0'' = \Delta_+ \sqrt{1 - \Delta_-^2/(J_1 - J_2)^2}$. [In calculating the curves in Fig.3 we have put in a nonvanishing $\delta = 0.3 - 0.5$ in Eq.(20) to smooth out the curves, and this results in a small and nonvanishing DOS inside of the threshold]. The first peak occurs at $\omega_0' = \Delta_+ \sqrt{1 - \Delta_-^2/(J_1 + J_2)^2}$. In the limit of $\delta = 0$, the peak is a logarithmic singularity, i.e.

$$N_s(\omega) = A_{\pm} \ln |\omega - \omega_0'| + B_{\pm}, \quad (21)$$

where A_{\pm}, B_{\pm} are nonsingular in ω and \pm refer to the high or low side of the singularity. A second logarithmic singularity occurs at $\omega = \omega_+'' = \sqrt{(J_1 + J_2)^2 + \Delta_+^2} + \Delta_-$, which is

outside of ω'_0 . Both singularities are less sharp than the $(\omega - \Delta)^{-1}$ singularity of a BCS superconductor, and a dip in the DOS curve occurs between them. The detail of this analysis will be given in the Appendix. It should be noted that the two sets of peaks only occur when $\lambda_{01} \neq \lambda_{02}$. For equal coupling strengths we find that $\Delta_1 = \Delta_2$ and the DOS follows the standard BCS behavior [3-5].

The tunneling characteristics at various temperatures are calculated by convoluting the DOS curve with the Fermi distribution factor:

$$\frac{dI(V)}{dV} \propto \int N_s(\omega - eV) \frac{\beta e^{\beta\omega}}{(e^{\beta\omega} + 1)^2} d\omega, \quad (22)$$

where e is quasiparticle charge and V is the bias. We show in Fig.4 a set of tunneling characteristics for the same set of material parameters used in Fig.2. The temperatures are marked on the curves. At elevated temperatures the fine details of the DOS curves tend to be smoothed away, with only a shallow dip left around zero bias. These curves resemble qualitatively the *ab*-direction tunneling data of BSSCO [9,10].

High- T_c materials all have short coherence lengths in the *c*-direction. Consequently, when tunneling in this direction, the data may be more representative of the topmost layer than the bulk. We simulate this effect by projecting out the DOS of the individual layers:

$$N_s^{(n)}(\omega) = N(0) \int \frac{s dk_z}{2\pi} \text{Im} \frac{-i\nu}{2c} \left[\frac{-\epsilon_1^2 + c \pm \Delta_+ \Delta_-}{\sqrt{\nu^2 + a_+}} + \frac{\epsilon_1^2 + c \mp \Delta_+ \Delta_-}{\sqrt{\nu^2 + a_-}} \right]_{\nu \rightarrow -i\omega + \delta}, \quad (23)$$

where the upper (lower) sign applies to $n = 1(2)$. The tunneling characteristics based on the projected DOS are shown in Figs.5 and 6. These curves are visibly different from those in Fig.4, especially the relative weight of the two peaks. Thus, depending which layer is exposed, the *c*-axis tunneling data may differ considerably from sample to sample and from the *ab*-axes data. In the next section we extend these considerations to the interlayer pairing model.

3. The Interlayer Pairing Model

The interlayer pairing model postulates that the Cooper pairs always reside in adjacent layers. The interaction Hamiltonian V which leads to this type of pairs is of the form

$$V = - \sum_j \sum_{\mathbf{k}\sigma} \sum_{\mathbf{k}'\sigma'} [\lambda_1 \psi_{j1\sigma}^\dagger(\mathbf{k}) \psi_{j2\sigma'}^\dagger(-\mathbf{k}) \psi_{j2\sigma'}(-\mathbf{k}') \psi_{j1\sigma}(\mathbf{k}') + \lambda_2 \psi_{j2\sigma}^\dagger(\mathbf{k}) \psi_{j+1,1\sigma'}^\dagger(-\mathbf{k}) \psi_{j+1,1\sigma'}(-\mathbf{k}') \psi_{j2\sigma}(\mathbf{k}')], \quad (24)$$

where $\lambda_{1,2}$ are the intracell and intercell coupling strengths, both are cut off at a common energy ω_\perp . It has been shown in Refs 3–5 that the interlayer pairing interaction favors singlet pairing, although in a certain range of parameter space the triplet pairing may emerge at a temperature below T_c . We will concentrate in this paper the large region of the parameter space in which the triplet state can be ignored altogether.

The quasiparticle Green's function matrix elements are defined the same way as in Eq.(3). We define two order parameters

$$\Delta_1 = \lambda_1 \sum_{\mathbf{k}'} \langle \psi_{j1\sigma}(\mathbf{k}') \psi_{j2,-\sigma}(-\mathbf{k}') \rangle, \quad (25)$$

$$\Delta_2 = \lambda_2 \sum_{\mathbf{k}'} \langle \psi_{j2,-\sigma}(-\mathbf{k}') \psi_{j+1,1\sigma}(\mathbf{k}') \rangle. \quad (26)$$

We can then write the inverse Green's function matrix as

$$G^{-1}(k, \nu) = \begin{pmatrix} i\nu - \xi_0(\mathbf{k}) & -g(k_z) & 0 & -\Delta_a e^{-i\phi(k_z)} \\ -g^*(k_z) & i\nu - \xi_0(\mathbf{k}) & -\Delta_b e^{i\phi(k_z)} & 0 \\ 0 & -\Delta_b^* e^{-i\phi(k_z)} & i\nu + \xi_0(\mathbf{k}) & g(k_z) \\ -\Delta_a^* e^{i\phi(k_z)} & 0 & g^*(k_z) & i\nu + \xi_0(\mathbf{k}) \end{pmatrix}, \quad (27)$$

with

$$\Delta_a = \Delta_1 e^{i[k_z d + \phi(k_z)]} + \Delta_2 e^{-i[k_z d' - \phi(k_z)]}, \quad (28)$$

$$\Delta_b = \Delta_1 e^{-i[k_z d + \phi(k_z)]} + \Delta_2 e^{i[k_z d' - \phi(k_z)]}. \quad (29)$$

The physical meaning of Δ_a , and Δ_b will be discussed later. In the ground state where Δ_1 and Δ_2 are in phase and real, we have $\Delta_b = \Delta_a^*$. The gap equations as derived in Ref.8 are:

$$\Delta_1 = \frac{\lambda_1}{\beta} \sum_{k\nu} \frac{1}{D} \{ [\nu^2 + \xi_0^2(k)] \Delta_a + \epsilon_{\perp}^2(k_z) \Delta_a^* + |\Delta_a|^2 \Delta_a \} e^{-i[k_z d + \phi(k_z)]}, \quad (30)$$

$$\Delta_2 = \frac{\lambda_2}{\beta} \sum_{k\nu} \frac{1}{D} \{ [\nu^2 + \xi_0^2(k)] \Delta_a + \epsilon_{\perp}^2(k_z) \Delta_a^* + |\Delta_a|^2 \Delta_a \} e^{i[k_z d' - \phi(k_z)]}. \quad (31)$$

The sums over ν are cut off at ω_{\perp} . The quantity D has the expression

$$D = (\nu^2 + \xi_0^2)^2 + 2\epsilon_{\perp}^2(\nu^2 - \xi_0^2) + \epsilon_{\perp}^4 + 2|\Delta_a|^2(\nu^2 + \xi_0^2) + \epsilon_{\perp}^2(\Delta_a^2 + \Delta_a^{*2}) + |\Delta_a|^4. \quad (32)$$

After integrating over the two-dimensional crystal momentum k , we obtain

$$\Delta_1 = \lambda_1 N(0) \frac{\pi}{\beta} \sum_{\nu} \int \frac{s dk_z}{2\pi} I(k_z) e^{-i[k_z d + \phi(k_z)]}, \quad (33)$$

$$\Delta_2 = \lambda_2 N(0) \frac{\pi}{\beta} \sum_{\nu} \int \frac{s dk_z}{2\pi} I(k_z) e^{i[k_z d' - \phi(k_z)]}, \quad (34)$$

where the integrand

$$I(k_z) = \frac{1}{2} \left\{ \left[\Delta_a + \frac{i\epsilon_{\perp}(k_z)}{c} \right] \frac{1}{\sqrt{\nu^2 + a_+}} + \left[\Delta_a - \frac{i\epsilon_{\perp}(k_z)}{c} \right] \frac{1}{\sqrt{\nu^2 + a_-}} \right\}. \quad (35)$$

These equations have structures similar to the intralayer pairing case, but the various quantities therein have different definitions:

$$c = [\nu^2 + (\text{Re}\Delta_a)^2]^{1/2},$$

and

$$a_{\pm} = |\Delta_a|^2 - \epsilon_{\perp}^2 \pm 2i\epsilon_{\perp}c. \quad (36)$$

We review briefly here the behavior of the the critical temperature as a function of hopping as discussed in detail in Refs.6 and 8. In the limit of zero hopping the critical temperature is determined by the stronger of the two coupling constants via the equation

$$\lambda > N(0)a_{\perp}(T_{c0}) = 1, \quad (37)$$

where, in analogy with Eq.(18), $a_{\perp}(T) = \ln(2\gamma\omega_{\perp}/\pi T)$. With increasing hopping, the critical temperature T_c diminishes steadily from T_{c0} . In the strong hopping limit, the asymptotic T_c is solved from

$$[N(0)a_{\perp}(T_c)]^{-1} = \frac{1}{4}\{\lambda_1 + (2 - \zeta^2)\lambda_2 + [\lambda_1^2 - 2(2 - 3\zeta^2)\lambda_1\lambda_2 + (2 - \zeta^2)^2\lambda_2^2]^{1/2}\}, \quad (38)$$

with $\zeta = J_1/J_2$. At zero temperature and zero hopping, only Δ_1 , which corresponds to the larger coupling strength λ_1 , is nonvanishing. For stronger hopping Δ_1 diminishes while Δ_2 grows, similar to the intralayer pairing case shown in Fig.1.

In Fig.7 we show the results of the numerical solutions of the finite temperature gap equations, Eqs.(33) and (34), for a set of parameters $\lambda_2/\lambda_1 = 0.5$, $\lambda_1 N(0) = 0.5$, $J_2/J_1 = 0.8$, and $J_1/T_{c0} = 1$. For these parameters $T_c = 0.95T_{c0}$. The dominant OP Δ_1 has the BCS temperature dependence, while the subordinate OP Δ_2 is small over the entire temperature range. This is the general behavior for weak to intermediately hopping, that one OP dominates over the other nearly completely. The pattern changes when hopping is increased, as shown in Fig.8 for a set of parameters $\lambda_2/\lambda_1 = 0.8$, $\lambda_1 N(0) = 0.5$, $J_1/J_2 = 0.4$, and $J_2/T_{c0} = 2$. It can be seen that Δ_2 is the stronger OP at low temperatures but loses its dominance at high temperatures. This type of competition between OP's, not seen in the intralayer pairing case, arises from the fact that the OP's are nonlocal and interact more effectively through the c -axis band dispersion than the local OP's of intralayer pairing. The nonlocal nature of the OP's also manifests itself in additional structures in the DOS and tunneling characteristics to be discussed next.

The expression for the DOS in the superconducting state as calculated from Eq.(19) is found to be, after integrating over \mathbf{k} :

$$N_s(0) = N(0) \int \frac{sd\mathbf{k}_z}{2\pi} \text{Im}(-i\nu) \left\{ \left[1 + \frac{i\epsilon_{\perp}}{\sqrt{\nu^2 + (\text{Re}\Delta_a)^2}} \right] \frac{1}{\sqrt{\nu^2 + a_+}} \right. \\ \left. + \left[1 - \frac{i\epsilon_{\perp}}{\sqrt{\nu^2 + (\text{Re}\Delta_a)^2}} \right] \frac{1}{\sqrt{\nu^2 + a_-}} \right\}_{\nu \rightarrow -i\omega + \delta}. \quad (39)$$

A set of DOS curves is shown in Fig.9 for model parameters used in Fig.7 except that J_1/T_{c0} ranges from 0.1 to 5. The bottommost curve for weak hopping is BCS-like, with peaks at $\pm\Delta_1$, i.e. the dominant OP. The topmost curve for strong hopping has threshold at $\pm(\Delta_1 - \Delta_2)$ and main peaks at $\pm(\Delta_1 + \Delta_2)$. The DOS curve increases continuously between the threshold and the peak on both sides. The origin of these features has been discussed in Ref.3–5, and is reiterated here using a different language. Recall the definition of Δ_a and its complex conjugate Δ_b in Eqs.(28) and (29). The real part of Δ_a or Δ_b given by:

$$\text{Re}\Delta_a = \Delta_1 \cos[k_z d + \phi(k_z)] + \Delta_2 \cos[k_z d' - \phi(k_z)], \quad (40)$$

which is an even function of k_z , is the intraband OP discussed in early papers,^{3–5} while the imaginary part, an odd function of k_z given by:

$$\text{Im}\Delta_a = \Delta_1 \sin[k_z d + \phi(k_z)] - \Delta_2 \sin[k_z d' - \phi(k_z)], \quad (41)$$

is the interband OP. It can be shown without much difficulty that the imaginary part vanishes in the strong hopping limit, leaving the intraband OP as the only order parameter. A little algebra yields that the extremal values of the right-hand-side of Eq(39) are $\Delta_1 \pm \Delta_2$ obtained at $k_z = 0$ and $k_z = \pm\pi/s$ respectively. Therefore, the inner structure reflects the *c*-axis versus *ab*-plane anisotropy of the gap function [3–5]. The main peaks are logarithmic singularities because of the k_z dependence of the gap function. In the intermediate hopping regime the DOS curves exhibit two sets of peaks in addition to structures inside of the inner peaks. It will be discussed in the Appendix that both sets of peaks are logarithmic singularities, but it is not straightforward to write down analytic expressions for the threshold and the positions of the singularities. Nonetheless, one can establish that, just like the intralayer pairing case, the outer peaks are associated with interband pairing. In contrast to the intralayer problem, however, the interband peaks may be stronger than

the intraband peaks, as demonstrated in Fig.10. The interpretation of the DOS curve is further complicated by the fact that both band dispersion and gap function dispersion contribute to the shape of the inner structure.

A set of simulated tunneling characteristics is shown in Fig.11. The general behavior is similar to the intralayer pairing case, that all features are smeared by thermal broadening. The curves bear close resemblance to the actual data on YBCO [10,11].

4. Summary and Conclusion

We have demonstrated that, simply as a result of the layered structure, the copper-oxide superconductors may have multiple peaks in their density-of-states and tunneling characteristics. Careful analyses of high quality tunneling data may shed light on the pairing mechanism. Because the short *c*-axis coherence lengths, the preferred way to take data is by tunneling out of the *a* and *b*-planes.

Our theoretical results, though limited in scope, may be applicable to real materials. Consider the case of YBCO with two identical CuO layers. If these are the only superconducting layers and the pairing mechanism is intralayer, we would conclude that the DOS should be BSC-like, in disagreement with the experiments [10,11]. We speculate, therefore, that either the CuO chains form another superconducting layer, or that the pairing mechanism is interlayer. One may be able to distinguish between the two possibilities by a detailed examination of the inner structure of the *ab*-plane tunneling data. The BSSCO system is inherently more complex owing to the additional BaO layers, which may be superconducting. Without solving the more than two layer model, we anticipate that the main DOS peaks are due to intraband pairing and should be logarithmic singularities. On the other hand, there should be more than one interband pairing features each associated with a different pair of bands, resulting in a less clear outer peak. Only the dip outside of the main peak remains as indication of the multilayer nature of the material. Again, any

additional structure inside the main peaks may hint at interlayer pairing. On the other hand, the absence of inner feature does not necessarily rule out interlayer pairing for the following reason. It has been shown in Ref.8 that if the hopping strength between two layers is stronger than the OP's, the two layers would act like one layer with intralayer pairing even though the pairing between the two layers is interlayer. In view of these complications, we would urge extra care in interpreting the tunneling data of high- T_c superconductors. It is interesting to note that the layered organic superconductor κ -(BEDT-TTF)₂Cu(NCS)₂ displays the same double peak tunneling characteristic although its critical temperature is merely 11 K [12]. We view this as added evidence that the crystal geometry, rather than the coupling mechanism, is the cause of the observed complex gap structure.

5. Acknowledgments

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Figure Captions

1. The dependence of the layer order parameters on the hopping strengths for a two-layer model with intralayer pairing. The model parameters are displayed in the graph.
2. The temperature dependence of the layer order parameters for a two-layer model with intralayer pairing. The model parameters are displayed in the graph.
3. A set of density-of-states (DOS) curves at zero temperature for a two-layer model with intralayer pairing. The model parameters are given in Fig.1. The curves are displaced vertically by 2 units successively.
4. Simulated tunneling characteristics for the two-layer model whose model parameters are in Fig.2. The curves are displaced vertically by 2 units successively.
5. Simulated tunneling characteristics from the layer 1 of the two-layer model studied in Figs.2 and 3. The curves are displaced vertically by 2 units successively.
6. Simulated tunneling characteristics from the layer 2 of the two-layer model studied in Figs.2 and 3. The curves are displaced vertically by 2 units successively.
7. The temperature dependence of the interlayer order parameters for a two-layer model with interlayer pairing. The model parameters are displayed in the graph.
8. The temperature dependence of the interlayer order parameters for a two-layer with a different set of model parameters. The model parameters are displayed in the graph. The OP Δ_2 dominates at low temperatures but becomes less than Δ_1 near T_c .
9. A set of DOS curves at zero temperature for a two-layer model with interlayer pairing. The model parameters are such that $\lambda_2/\lambda_1 = 0.5$, $\lambda_1 N(0) = 0.5$, $J_1/J_2 = 0.8$, and J_1/T_{c0} ranging from 0.1 to 5. The curves are displayed vertically by 2 units successively.
10. A set of DOS curves at zero temperature for a two-layer model with interlayer pairing. The model parameters are such that $\lambda_2/\lambda_1 = 0.8$, $\lambda_1 N(0) = 0.5$, $J_1/J_2 = 0.4$,

and J_1/T_{c0} ranging from 0.1 to 5. The curves are displayed vertically by 2 units successively.

11. Simulated tunneling characteristics for a two-layer model with interlayer pairing. The model parameters are given in Fig.9.

Appendix

We analyze here the structure of the DOS curves for the two-layer model with intralayer or interlayer pairing. The expression for $N_s(\omega)$ for the intralayer model is given in Eq.(20). After making the analytical continuation to real frequencies, we find that the right-hand side of Eq.(20) have singularities determined by the zeros of the factors $a_+ - \omega^2$, $a_- - \omega^2$, and c , where

$$c = \sqrt{\Delta_+^2 \Delta_-^2 + \epsilon_\perp^2 (\omega^2 - \Delta_+^2)}, \quad (A1)$$

and a_\pm are given in Eq.(16). The factor c has a zero at

$$\omega_0 = \Delta_+ \sqrt{1 - \frac{\Delta_-^2}{\epsilon_\perp^2}}, \quad (A2)$$

which is real for $\epsilon_\perp > \Delta_-$. The quantity ϵ_\perp , given in Eq.(8), is a function of the c -axis momentum k_z . Consequently ω_0 varies from its maximum $\omega'_0 = \Delta_+ \sqrt{1 - \Delta_-^2 / (J_1 + J_2)^2}$ obtained at $k_z = 0$ to its minimum $\omega''_0 = \Delta_+ \sqrt{1 - \Delta_-^2 / (J_1 - J_2)^2}$ obtained at $k_z = \pm\pi/s$. The zeros of $a_\pm - \omega^2$ are more subtle. One can show after some manipulations that

$$(a_+ - \omega^2)(a_- - \omega^2) = (\omega_+^2 - \omega^2)(\omega_-^2 - \omega^2), \quad (A3)$$

where

$$\omega_\pm = \sqrt{\epsilon_\perp^2(k_z) + \Delta_+^2} \pm \Delta_-. \quad (A4)$$

Thus the zeros of $a_\pm - \omega^2$ are contained in the set $\pm\omega_\pm$. Further analysis reveals that ω_+ is a zero of $a_+ - \omega^2$ only. The quantity ω_- , however, is a zero of $a_+ - \omega^2$ or $a_- - \omega^2$ depending on whether ϵ_\perp^2 is greater than or less than the following quantity:

$$b = \Delta_- \sqrt{\epsilon_\perp^2 + \Delta_+^2}. \quad (A5)$$

Bear in mind that ϵ_\perp is a function of k_z , it follows that both ω_\pm vary between their maximum values $\omega'_\pm = \sqrt{(J_1 + J_2)^2 + \Delta_+^2} \pm \Delta_-$ at $k_z = 0$ and minimum values $\omega''_\pm =$

$\sqrt{(J_1 - J_2)^2 + \Delta_+^2} \pm \Delta_-$ at $k_z = \pm\pi/s$. The zero at ω_- may shift from one term in the square bracket of Eq.(20) to the other depending on the value of k_z . The following inequality $\omega_+ \geq \omega_- \geq \omega_0$ is satisfied for all values of k_z .

We will make use of this set of information to analyze the DOS curves. In the weak coupling limit the quantity c is real for all values of ω , and the quantities $\omega_{\pm} = \Delta_1, \Delta_2$ respectively. Therefore, the singularities of $N_s(\omega)$ are the order parameters of the individual layers. In the strong hopping limit the quantity $\omega_0 = \Delta_+$ and ω_{\pm} are so large that they are out of the picture. The only singularity in DOS corresponds to the energy gap in the band representation. For intermediate hopping one must study the singular behavior on individual basis. As an example, consider the case $J_1/T_{c0} = 1$ in Fig.4. The input data are, $\Delta_1 = 1.7416, \Delta_2 = 1.2927, J_1 = 1, J_2 = 0.3$, all in units of T_{c0} . From these we determine at $k_z = 0$ that $\omega'_+ = 2.2823, \omega'_- = 1.8333$ and $\omega'_0 = 1.2131$. The inequality $\epsilon_{\perp}^2 > b$ is satisfied, b is defined in Eq.(A5). At the zone boundary, $k_z = \pm\pi/s$, we find $\omega''_+ = 1.9191, \omega''_- = 1.0211, \omega''_0 = 0.9917$, and $\epsilon_{\perp}^2 < b$. Thus, the following picture emerges. For $\omega < \omega''_0$ the factor c is real and $N_s(\omega) = 0$ because the integrand in Eq.(20) vanishes. In the numerical calculation a small but finite $\delta = .05$ is used to help smooth the curves, but this also causes the $N_s(\omega)$ curves to appear nonvanishing inside of the threshold. For ω just beyond the threshold, the DOS increases rapidly because a larger range of k_z near the zone boundary now contributes. This trend continues until ω reaches ω'_0 where the entire zone of k_z contributes to the integral in Eq.(20). It is not difficult to show that the k_z integral actually diverges logarithmically, which implies the asymptotic property of $N_s(\omega)$ in Eq.(21). It should be noted that the main peak is contained in the factor c , as in the strong hopping case.

A similar reasoning applies to the second logarithmic singularity at ω'_+ . This singularity is contained in the factor $a_+ - \omega^2$, reminiscent of the weak hopping case except that

the band splitting contained in the expression for ω_+ (Eq.(A4)) is not negligible. For this reason as well as that this feature disappears in the strong hopping limit, we identify it as the interband pairing contribution to $N_s(\omega)$. Because $\omega'_0 > \omega''_-$ the singularity at ω_- is overwhelmed by the main peak.

The singularities for the interlayer pairing problem are investigated in the same manner. The expression for $N_s(\omega)$ is given in Eq.(39), with a_{\pm} in Eq.(36). One singularity can be readily identified as $\omega_0 = |\text{Re}\Delta_a(k_z)|$, which is the intraband gap function. As in the intralayer pairing model, the k_z dispersion of this singularity determines the threshold, the inner structure and the nature of the main peak in the strong hopping case. Additional singularities are found from the relation:

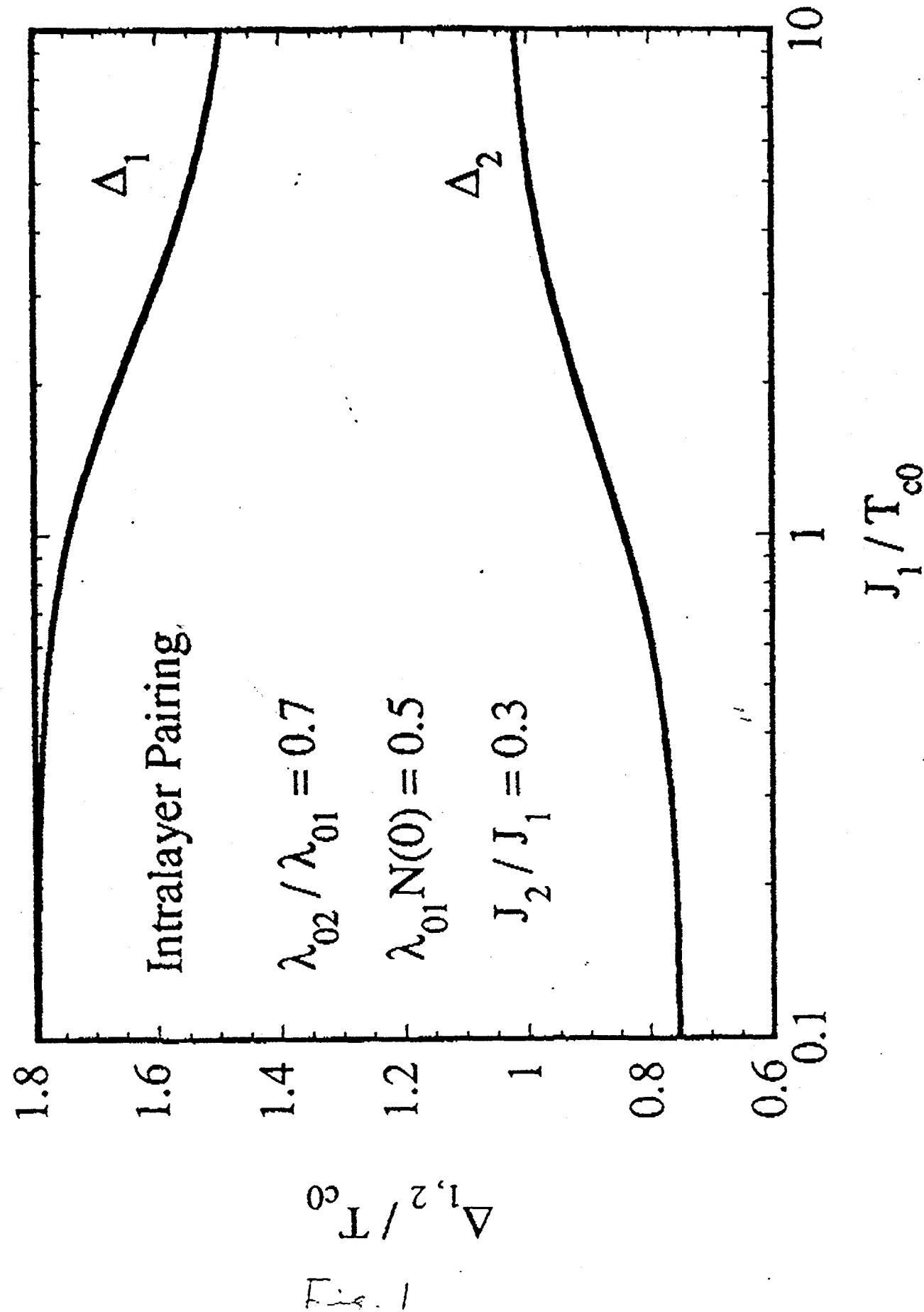
$$(a_+ - \omega^2)(a_- - \omega^2) = (\omega_+^2 - \omega^2)(\omega_-^2 - \omega^2), \quad (A6)$$

where

$$\omega_{\pm}^2 = (\text{Re}\Delta_a)^2 + (\epsilon_{\perp} \pm \text{Im}\Delta_a)^2. \quad (A7)$$

The k_z dependence of ω_{\pm} depends on both the gap function dispersion and the band dispersion, making the outer peak difficult to locate analytically. Numerically, we find that the outer peak is at the maximum value of ω_+ , which occurs in the middle of the c -axis Brillouin zone.

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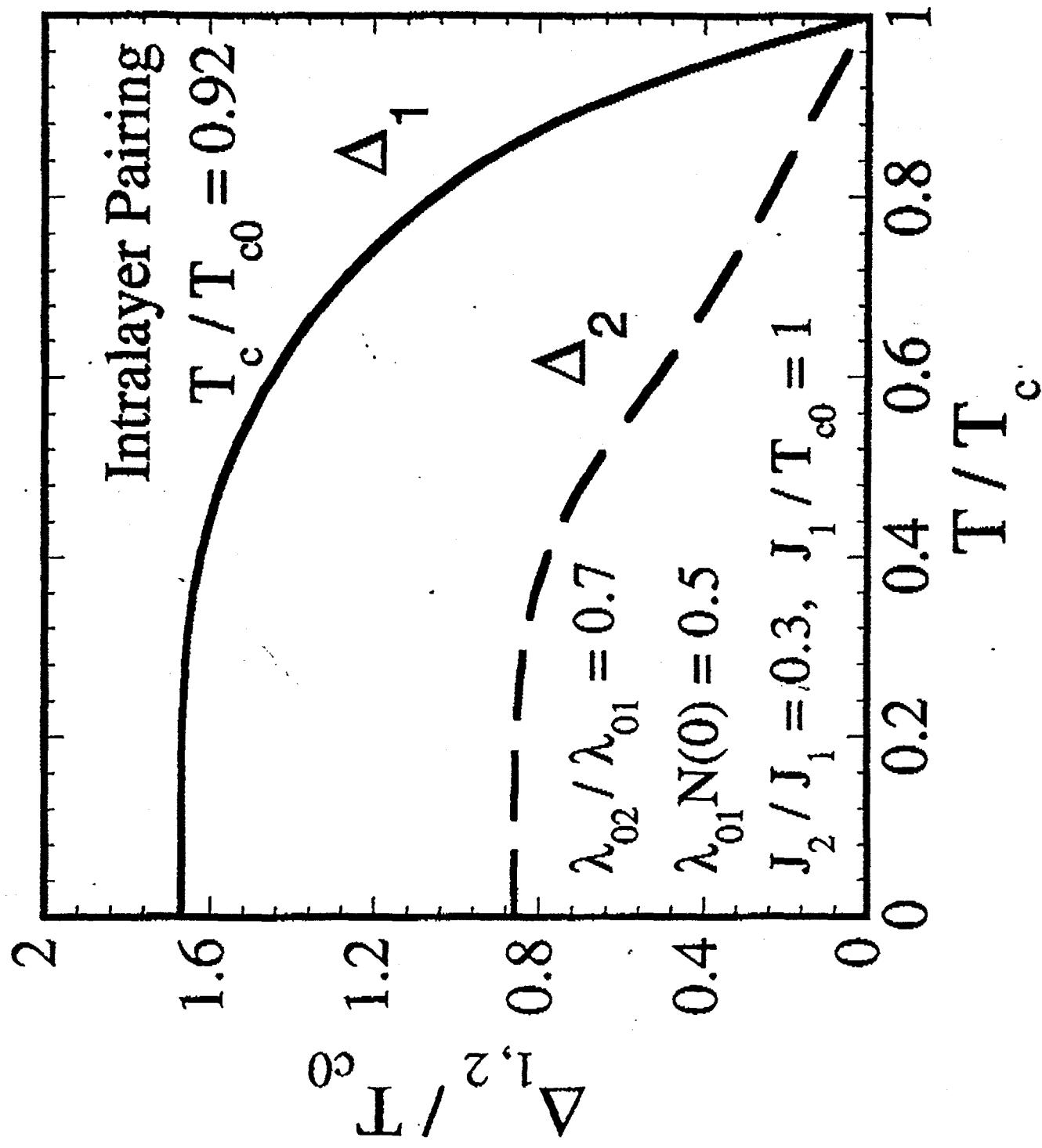


Fig 2

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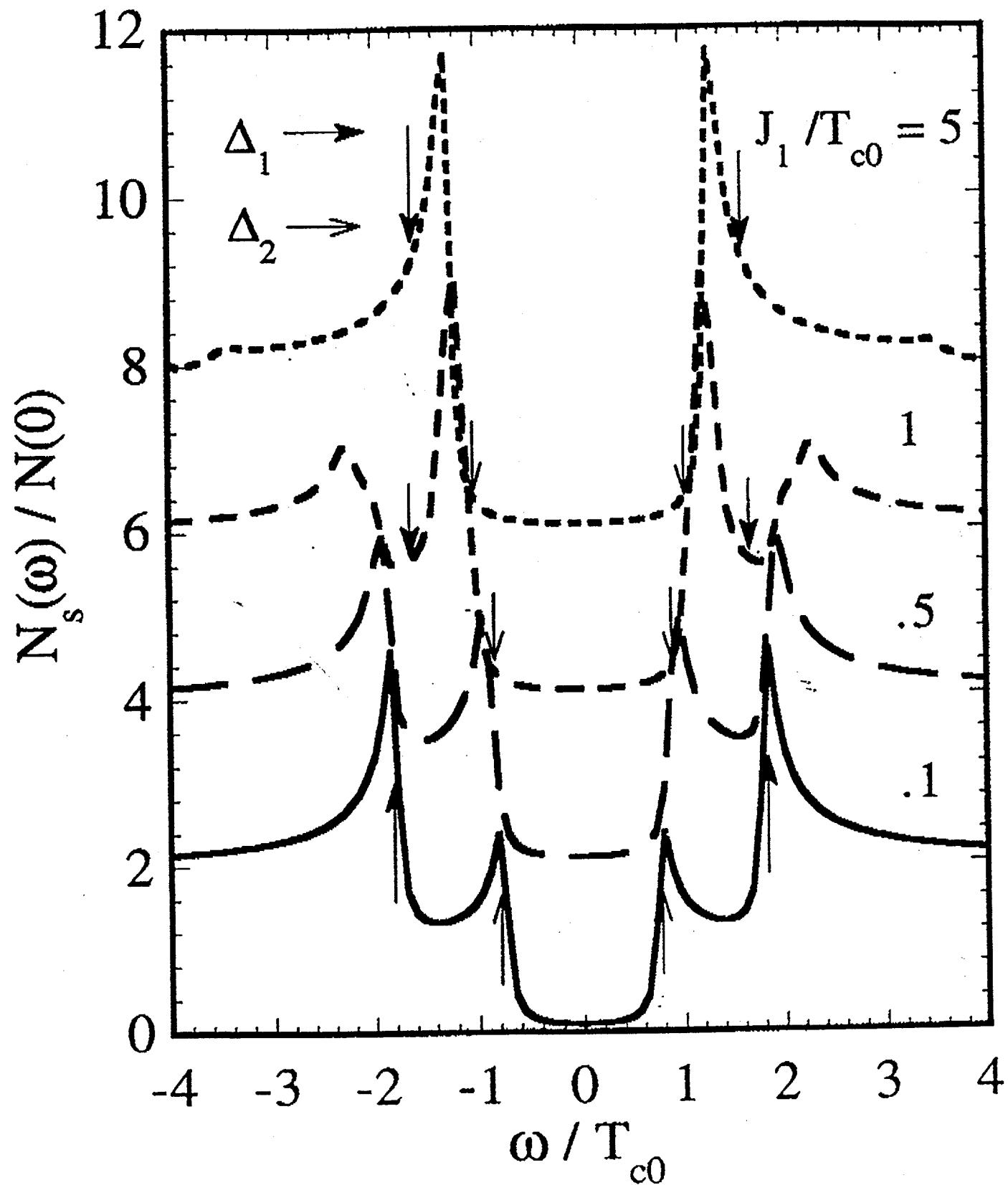


Fig. 3

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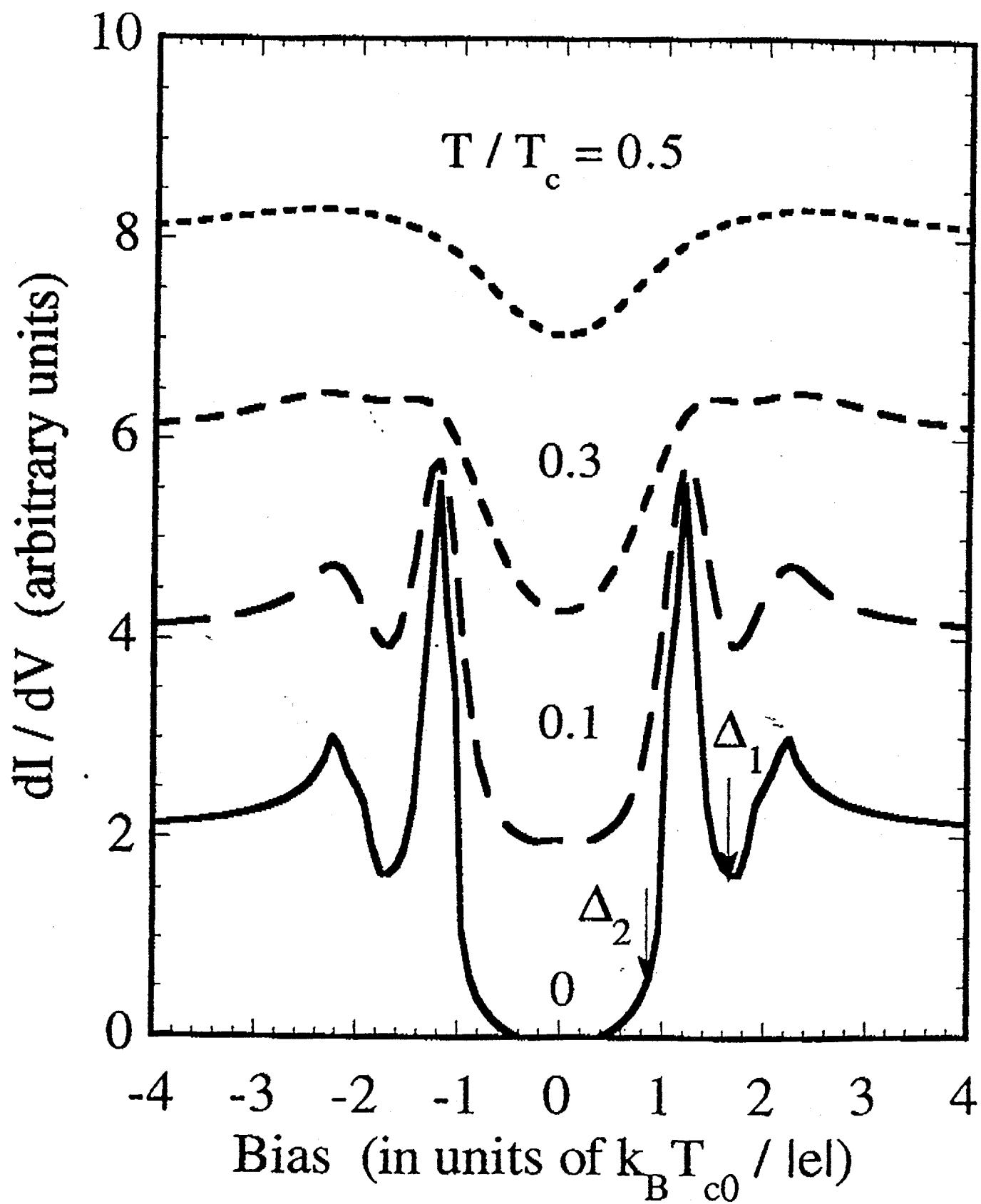


Fig. 4

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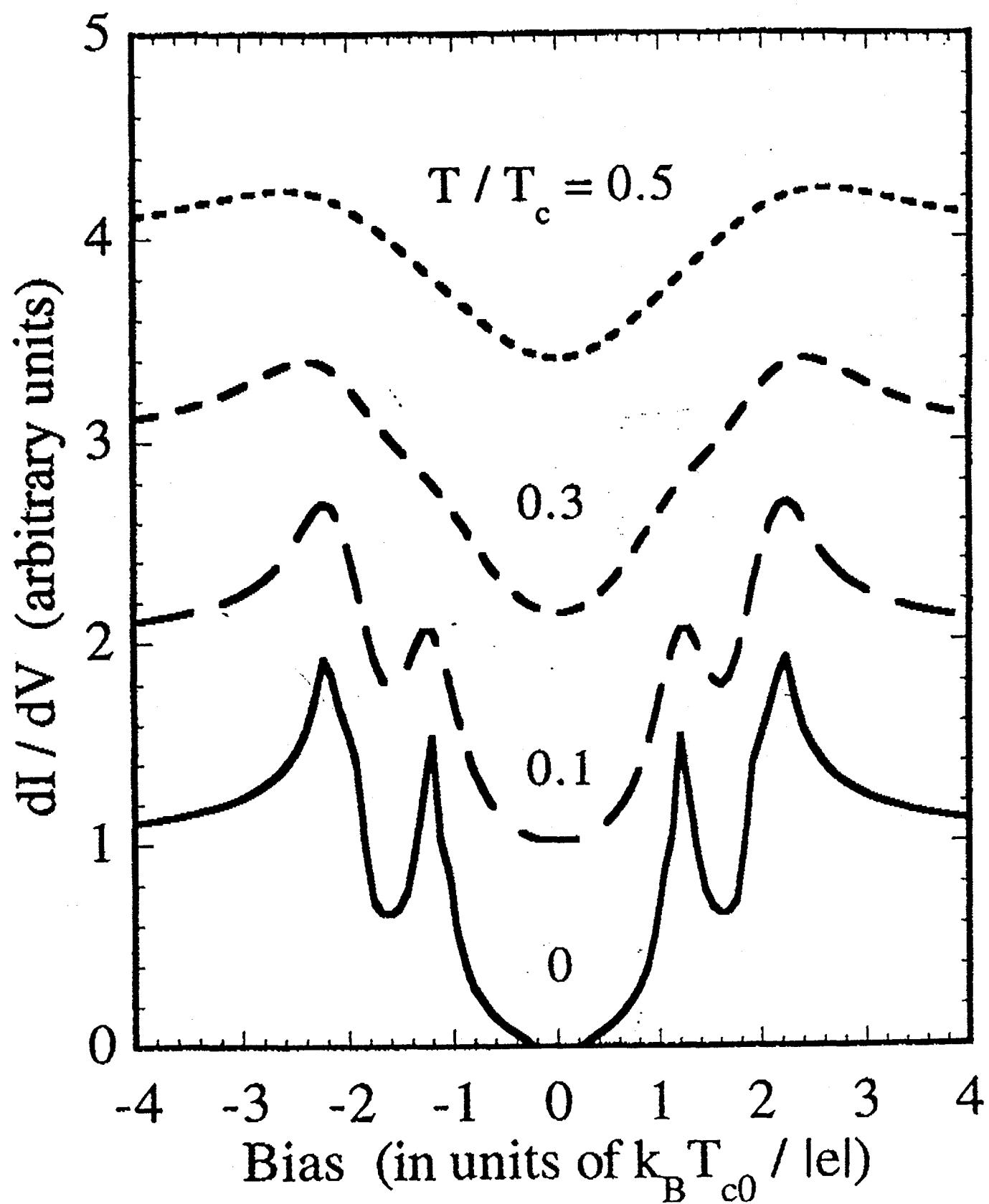


Fig. 5

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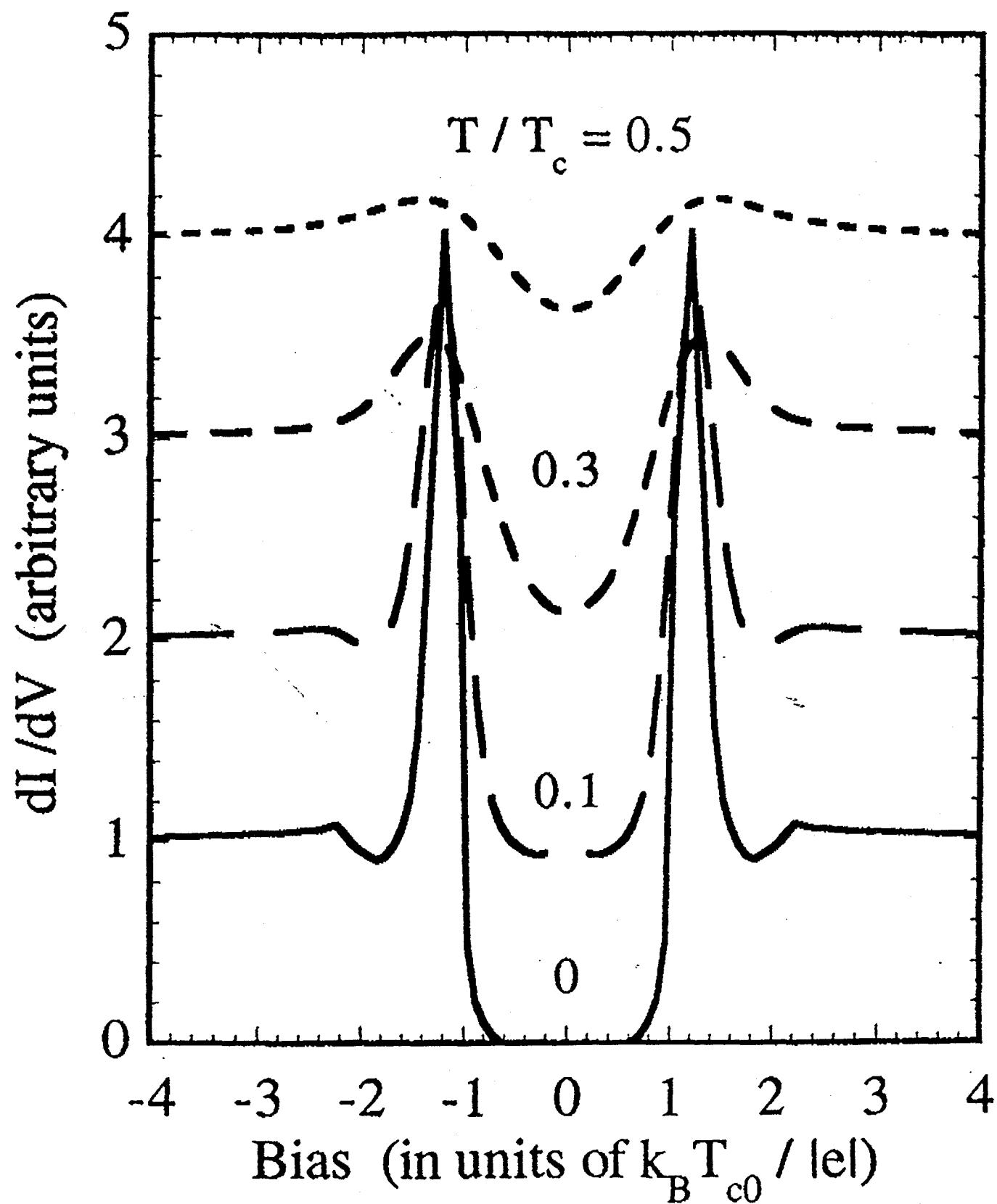


Fig. 6

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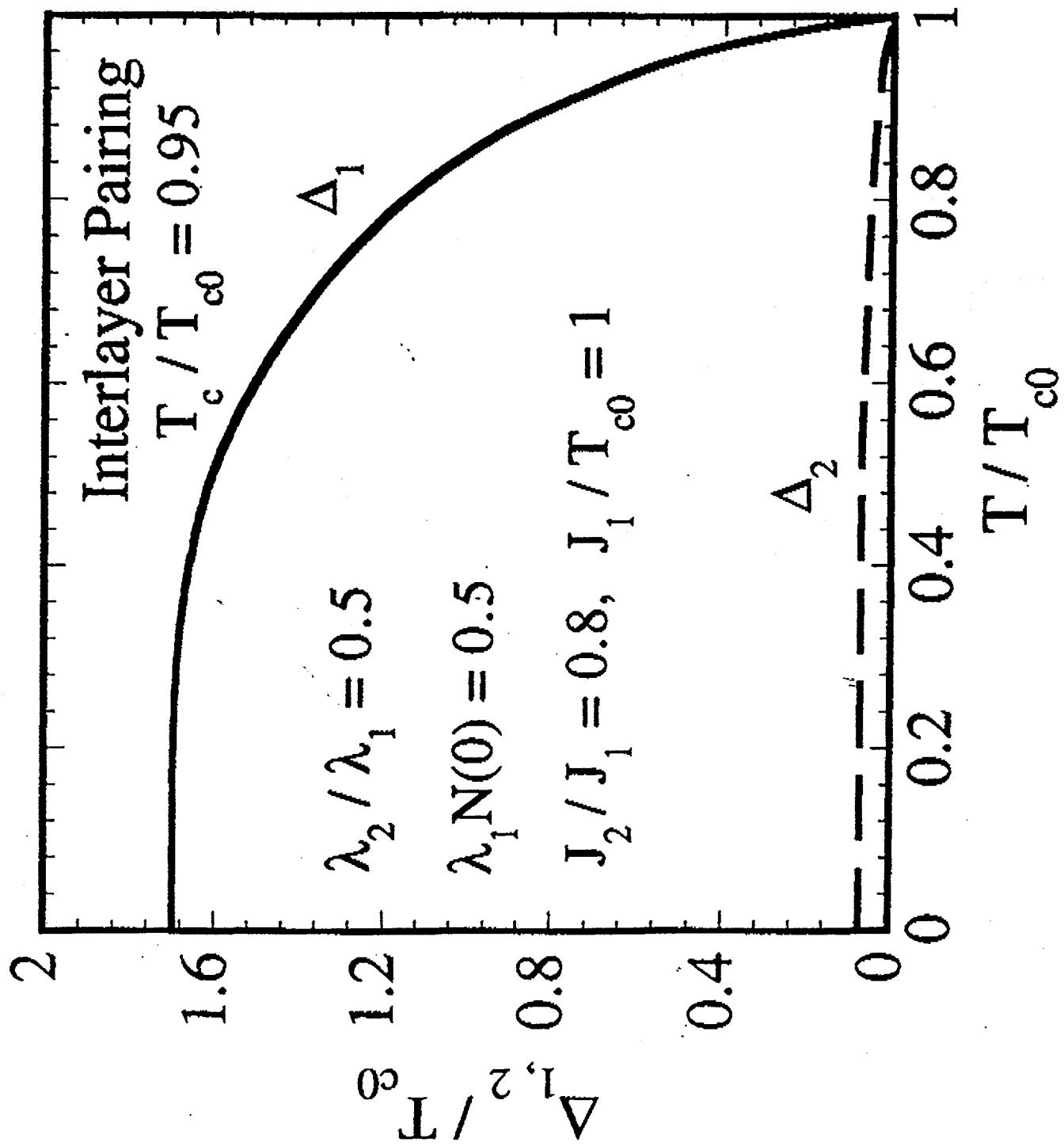


Fig. 7

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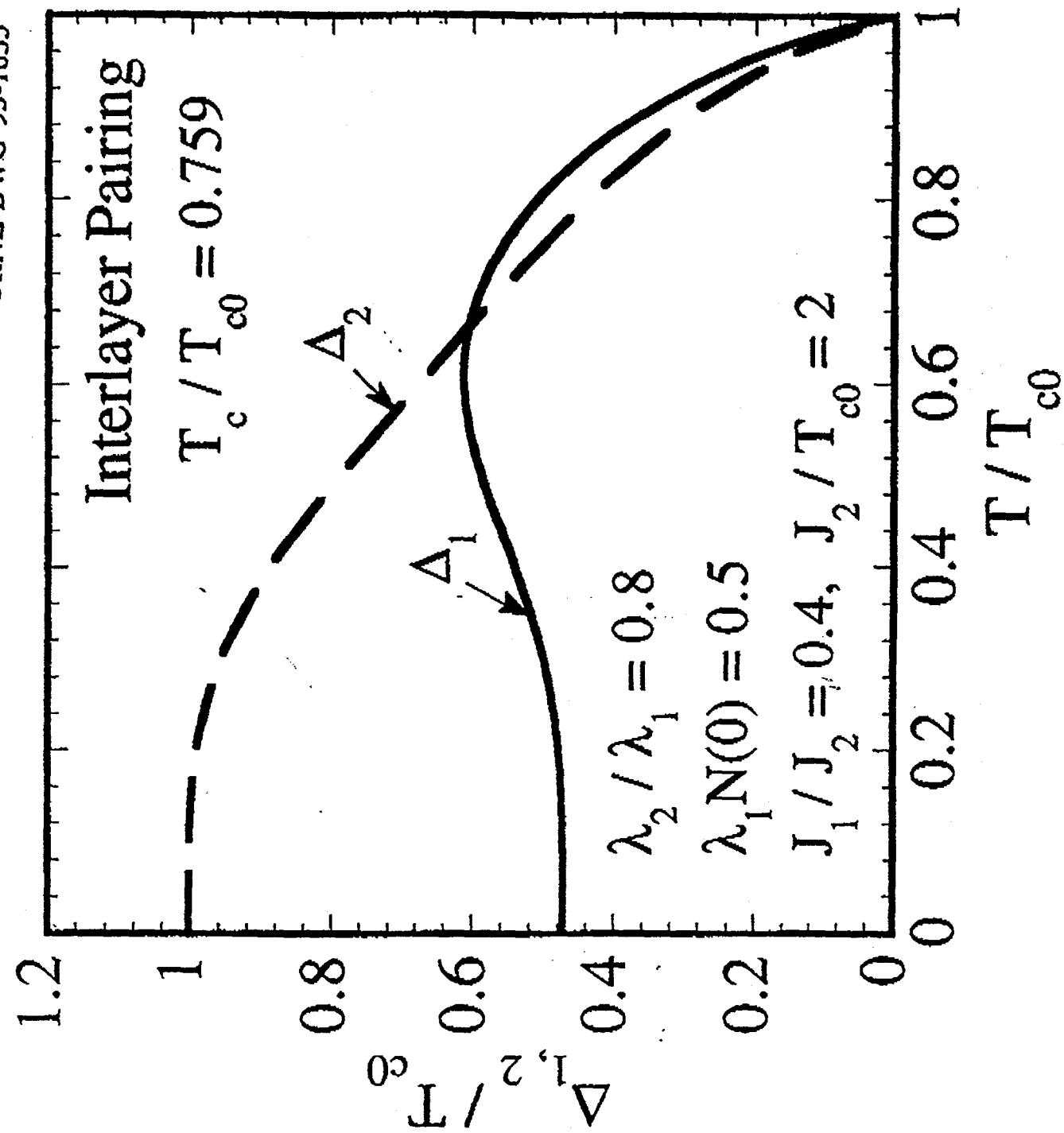


Fig. 8

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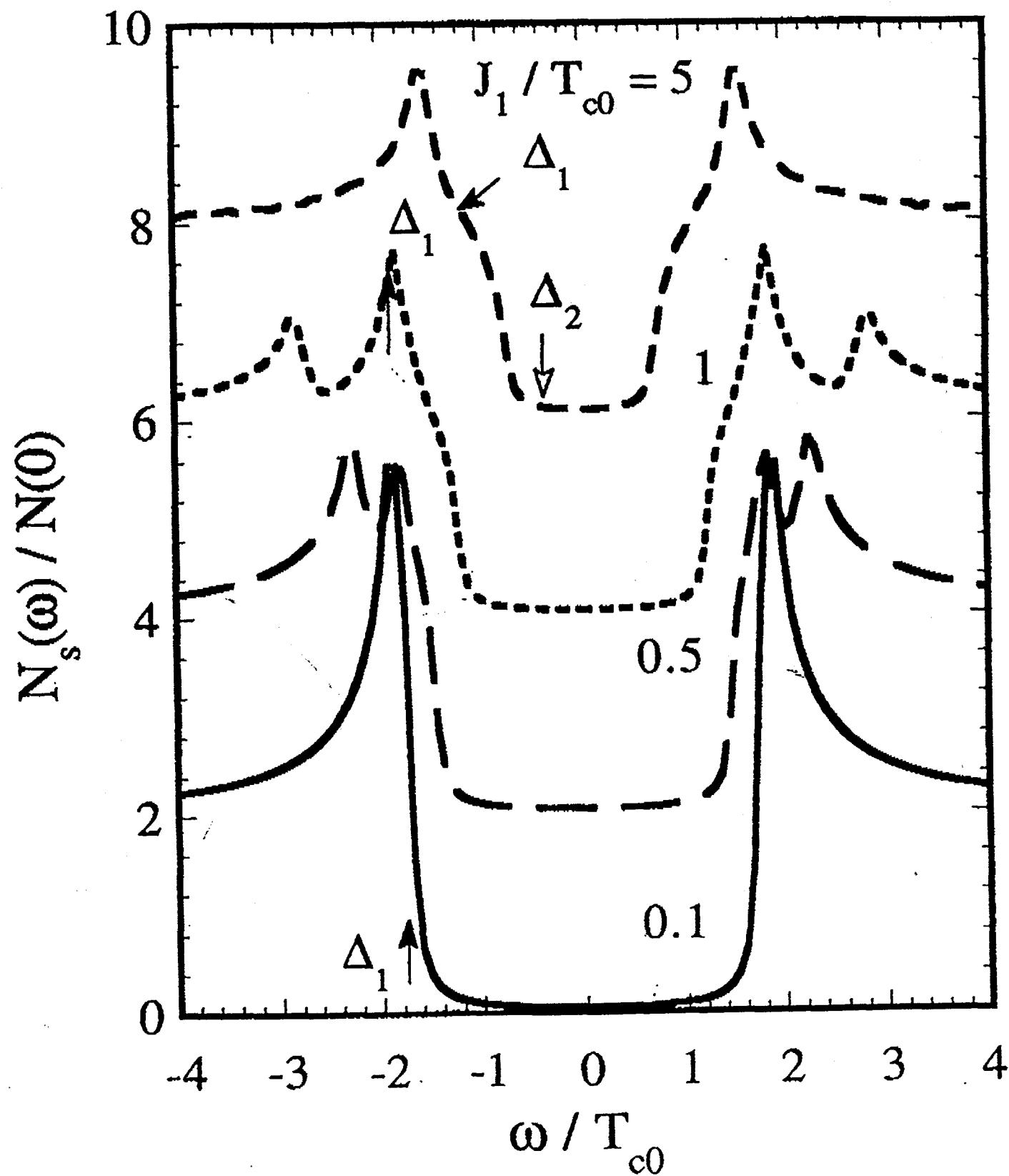


Fig. 9

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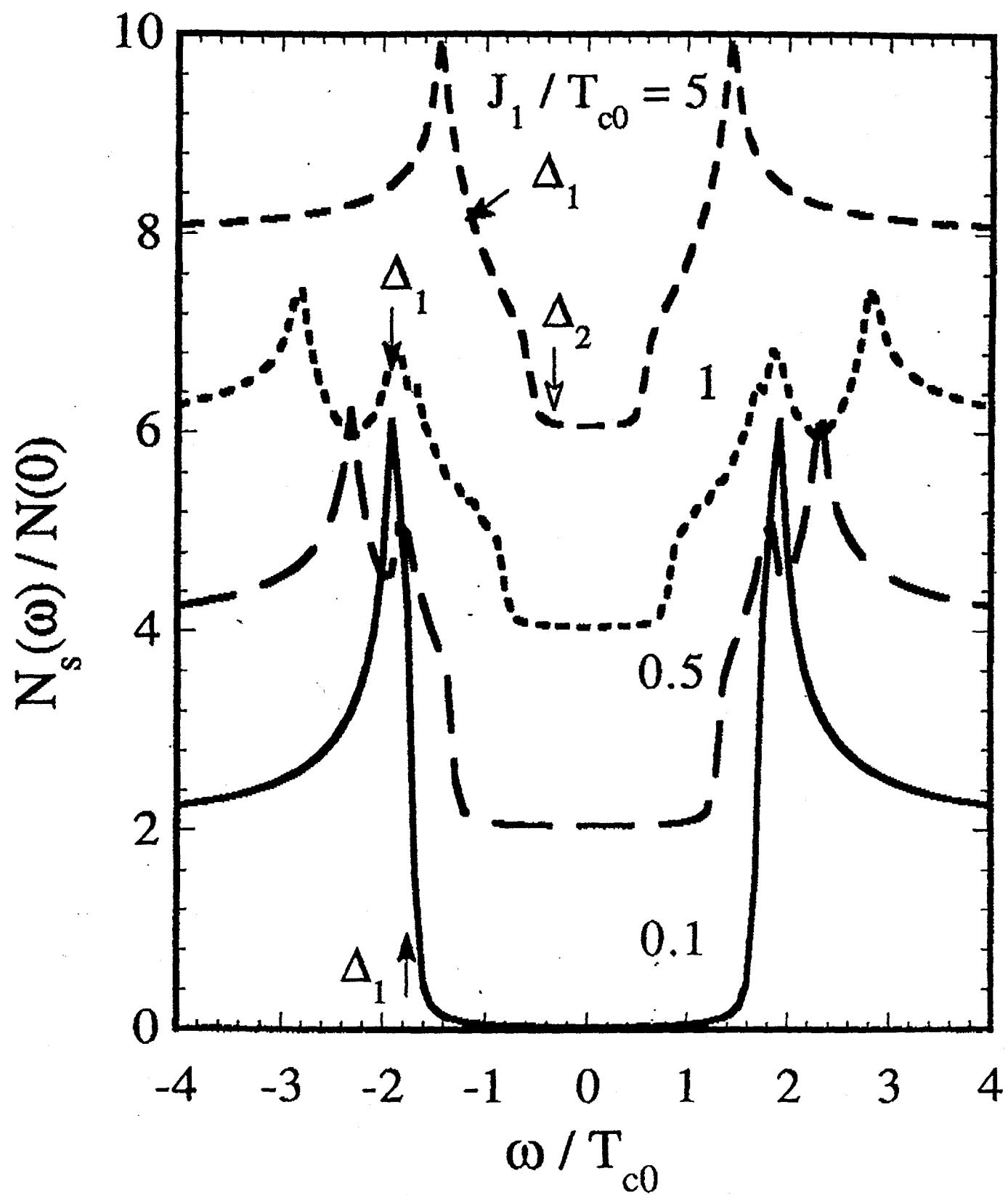


Fig. 10

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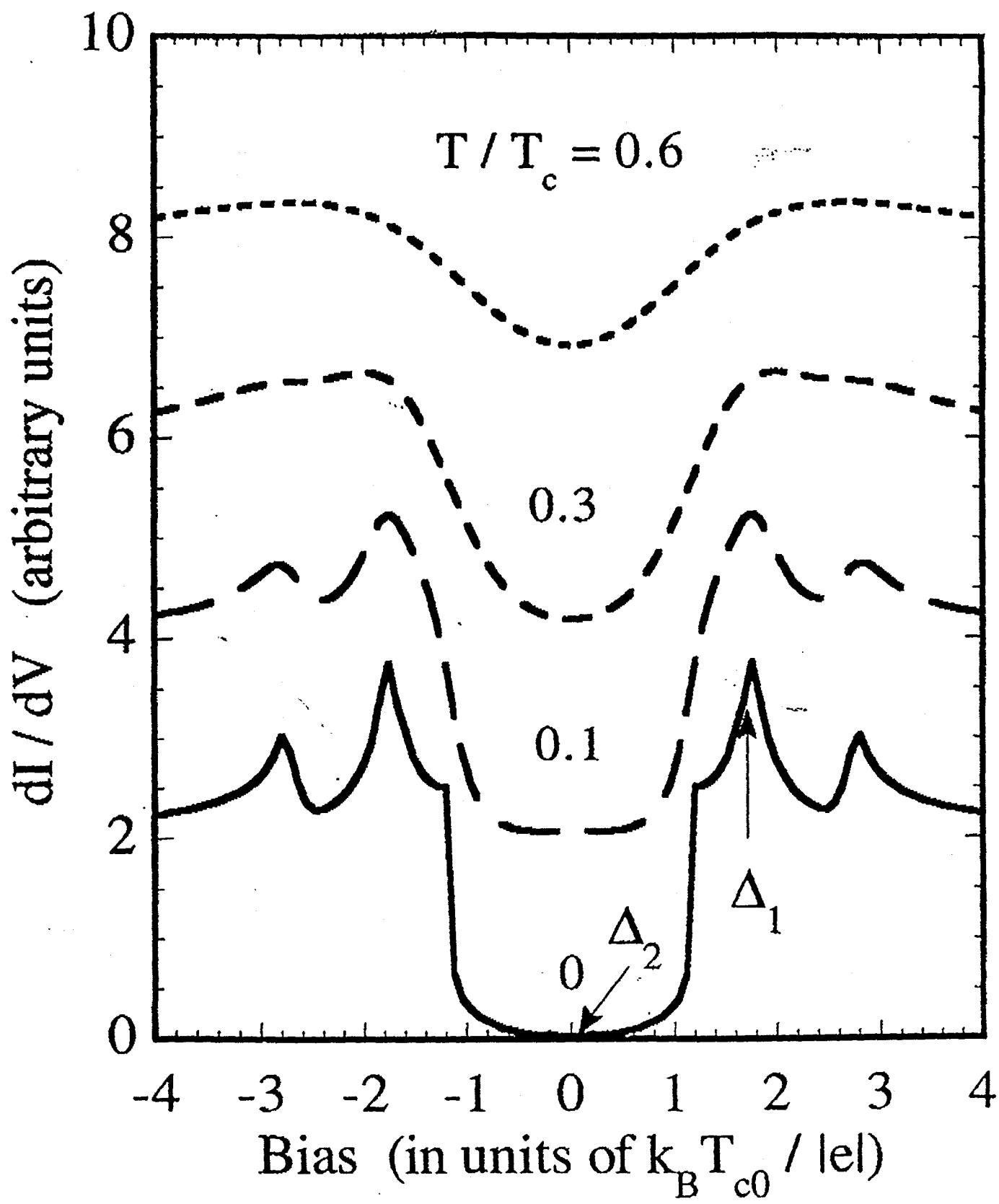


Fig. 11